

IPW60R190E6 Information


For Reference Only

Part Number [IPW60R190E6](#)
Manufacturer Infineon Technologies
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 600V 20.2A TO247
Package TO-247-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


IPW60R190E6 Specifications

Manufacturer Part Number	IPW60R190E6
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vds)	600V
Current - Continuous Drain (Id) @ 25°C	20.2A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.5V @ 630µA
Gate Charge (Qg) (Max) @ Vgs	63nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1400pF @ 100V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	151W (Tc)
Rds On (Max) @ Id, Vgs	190 mOhm @ 9.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO247-3
Package / Case	TO-247-3

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IPW60R190E6 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IPW60R190E6 Payment Methods



IPW60R190E6 Shipping Methods



If you have any question about IPW60R190E6, please do not hesitate to contact us!

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